

AOZ6233 0.35Ω Low-Voltage Dual-SPDT Analog Switch

## **General Description**

The AOZ6233 is a 0.35 $\Omega$  low-voltage Dual Single Pole Double Throw (SPDT) analog switch. The AOZ6233 operates from a single 1.65V to 3.6V supply. It features an ultra-low On Resistance of 0.35 $\Omega$  at a +2.7V supply and 25°C. The AOZ6233 is designed for break-beforemake operation.

### **Features**

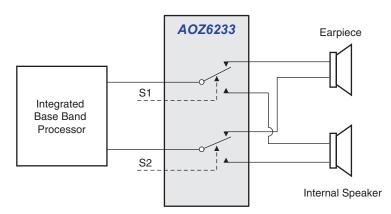
- Typical 0.35 $\Omega$  On Resistance (R<sub>ON</sub>) for +2.7V supply
- $0.15\Omega$  maximum R<sub>ON</sub> flatness for +2.7V supply
- 1.6mm x 2.1mm QFN package
- Broad V<sub>CC</sub> operating range
- Low THD (0.02% typical for 32Ω load)
- High current handling capability (350mA continuous current under 3.3V supply)

### **Applications**

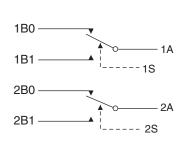
- Cell phone
- PDA
- Portable media player



# **Typical Application**



# **Pin Configuration**





## **Ordering Information**

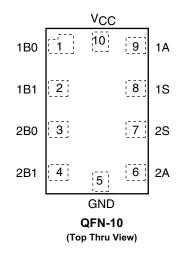
Part Number	Ambient Temperature Range	Package	Environmental
AOZ6233QI	-40°C to +85°C	QFN-10	RoHS Compliant
			Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

Please visit www.aosmd.com/web/quality/rohs\_compliant.jsp for additional information.

# **Pin Configuration**



## **Pin Description**

Pin Name	Function
1A, 2A, 1B0, 1B1, 2B0, 2B1	Data Ports
1S, 2S	Control Input

## **Truth Table**

Logic Input	Function
0	B0 Connected to A
1	B1 Connected to A

## **Absolute Maximum Ratings**

Exceeding the Absolute Maximum ratings may damage the device.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	-0.5V to +5.5V
V <sub>S</sub>	Switch Voltage <sup>(1)</sup>	-0.5 to V <sub>CC</sub> + 0.5V
V <sub>IN</sub>	Input Voltage <sup>(1)</sup>	-0.5 to V <sub>CC</sub>
Ι <sub>ΙΚ</sub>	Minimum Input Diode Current <sup>(2)</sup>	-50mA
I <sub>SW</sub>	Switch Current	350mA
I <sub>SWPEAK</sub>	Peak Switch Current (Pulsed at 1ms duration, <10% Duty Cycle)	500mA
T <sub>STG</sub>	Storage Temperature Range	-65°C to +150°C
Т <sub>Ј</sub>	Maximum Junction Temperature	+150°C
ΤL	Lead Temperature (Soldering, 10 seconds)	+260°C
ESD	Human Body Model	8000V
	Charged Device Model	1000V

## **Recommend Operating Ratings**

The device is not guaranteed to operate beyond the Maximum Operating Ratings.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	1.65V to +3.6V
V <sub>IN</sub>	Control Input Voltage <sup>(3)</sup>	0V to V <sub>CC</sub>
V <sub>SW</sub>	Switch Input Voltage	0V to V <sub>CC</sub>
T <sub>A</sub>	Operating Temperature	-40°C to +85°C

Notes:

1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

2. Negative current should not exceed minimum negative value.

3. Unused inputs must be held HIGH or LOW. They may not float.



### **DC Electrical Characteristics**

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units
V <sub>IH</sub>	Input Voltage HIGH		2.7 to 3.6	2.0			V
			2.3 to 2.7	1.7			
			1.65 to 1.95	$0.65 \times V_{CC}$			
V <sub>IL</sub>	Input Voltage LOW		2.7 to 3.6			0.8	V
			2.3 to 2.7			0.7	
			1.65 to 1.95			$0.35  \mathrm{xV_{CC}}$	
I <sub>IN</sub>	Control Input Leakage	$V_{IN} = 0V$ to $V_{CC}$	1.65 to 3.6	-0.5		0.5	μA
I <sub>NO(OFF)</sub> , I <sub>NC(OFF)</sub>	Off-Leakage Current of Port $nB_0$ and $nB_1$	nA = 0.3V, 3.3V, nB0 or nB1 = 0.3V, 3.3V or floating	3.6	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
I <sub>A(ON)</sub>	On Leakage Current of Port 1A and 2A	nA = 0.3V, 3.3V, nB0 or nB1 = 0.3V, 3.3V or floating	3.6	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
R <sub>ON</sub>	Switch On Resistance <sup>(4)</sup> See Figure 1	I <sub>OUT</sub> = 100mA, nB0 or nB <sub>1</sub> = 0V, 0.7V, 2.0V, 2.7V	2.7		0.35	0.60	Ω
		I <sub>OUT</sub> = 100mA, nB0 or nB1 = 0V, 0.7V, 1.6V, 2.3V	2.3		0.40	0.70	
		I <sub>OUT</sub> = 100mA, nB0 or nB1 = 0.8V	1.65		1.0	3.0	
$\Delta R_{ON}$	On Resistance Matching	I <sub>OUT</sub> = 100mA, nB0 or	2.7		0.040	0.075	Ω
	Between Channels <sup>(5)</sup>	nB1 = 0.7V	2.3		0.040	0.080	
			1.65		0.1		
R <sub>FLAT(ON)</sub>	On Resistance Flatness <sup>(6)</sup>	I <sub>OUT</sub> = 100mA, nB0 or	2.7			0.15	Ω
		$nB1 = 0V$ to $V_{CC}$	2.3			0.3	1
			1.65		1.6		1
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = 0V \text{ or } V_{CC}, I_{OUT} = 0A$	3.6	-500		500	nA
I <sub>CCT</sub>	Increase in I <sub>CC</sub> per Input	V <sub>IN</sub> = 1.8V	3.6		75		μA
		V <sub>IN</sub> = 2.6V	1		5		1

#### Notes:

4. On resistance is determined by the voltage drop between A and B pins at the indicated current through the switch.

5.  $\Delta R_{ON} = R_{ONmax} - R_{ONmin}$  measured at identical V<sub>CC</sub>, temperature, and voltage.

6. Flatness is defined as the difference between the maximum and minimum value of R<sub>ON</sub> over the specified range of conditions.



## **AC Electrical Characteristics**

All typical values are at 25°C unless otherwise specified.

Symbol	ol Parameter Condition		V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units
t <sub>ON</sub>	Turn-On Time	nB0 or nB1 = 1.5V, $R_L = 50\Omega$ ,	2.7 to 3.6		40.0	50.0	ns
		C <sub>L</sub> = 35pF			50.0	55.0	
			1.65 to 1.95		75.0	90.0	
t <sub>OFF</sub>	Turn-Off Time	nB0 or nB1 = 1.5V, $R_{L} = 50\Omega$ ,	2.7 to 3.6		10.0	25.0	ns
		C <sub>L</sub> = 35pF	2.3 to 2.7		20.0	25.0	
			1.65 to 1.95		50.0	55.0	
t <sub>BBM</sub>	Break-Before-Make Time	nB0 or nB1 = 1.5V, $R_{L} = 50\Omega$ ,	2.7 to 3.6	2.0	17.0		ns
		C <sub>L</sub> = 35pF		2.0	15.0		
			1.65 to 1.95	2.0	12.0		
Q	Charge Injection	$\begin{array}{l} C_{L} = 100pF, \ V_{GEN} = 0V, \\ R_{GEN} = 0\Omega \end{array}$	1.65 to 3.6		9.0		рС
OIRR	Off Isolation	$f = 100 \text{kHz}, \text{R}_{\text{L}} = 50\Omega,$ $\text{C}_{\text{L}} = 5 \text{pF} \text{ (Stray)}$	1.65 to 3.6		-95		dB
Xtalk	Crosstalk	$f = 100 \text{kHz}, \text{R}_{\text{L}} = 50\Omega,$ $C_{\text{L}} = 5\text{pF} \text{ (Stray)}$	1.65 to 3.6		-95		dB
BW	-3dB Bandwidth	$R_L = 50\Omega$	1.65 to 3.6		45.0		MHz
THD	Total Harmonic Distortion	$ \begin{array}{l} R_{L} = 32\Omega, \ V_{IN} = 2V_{pk-pk}, \\ f = 20Hz \ to \ 20kHz \end{array} $	2.7 to 3.6		0.024		%
		$\begin{aligned} R_{L} &= 32\Omega,  V_{IN} = 1.5V_{pk-pk}, \\ f &= 20Hz \text{ to } 20kHz \end{aligned}$	2.3 to 2.7		0.015		
		$\label{eq:RL} \begin{split} R_{L} &= 32\Omega, \ V_{IN} = 1.2V_{pk-pk}, \\ f &= 20Hz \ to \ 20kHz \end{split}$	1.65 to 1.95		0.35		

# Capacitance

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units
C <sub>IN</sub>	Control Pin Input Capacitance	f = 1MHz	0.0		4		pF
C <sub>OFF</sub>	B Port Off Capacitance	f = 1MHz	3.3		22		pF
C <sub>ON</sub>	A Port On Capacitance	f = 1MHz	3.3		140		pF



# **Typical Performance Characteristics**

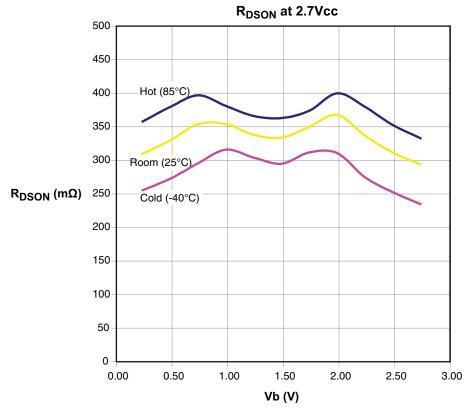
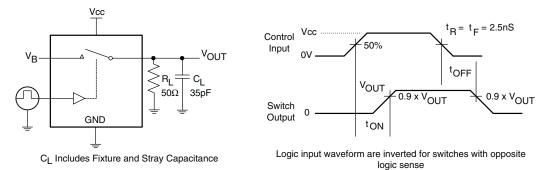
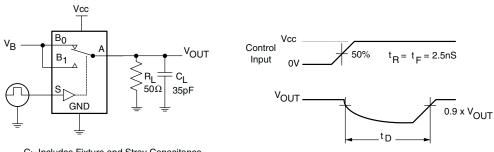


Figure 1. Switch On Resistance

# **AC Loading and Waveforms**







CL Includes Fixture and Stray Capacitance



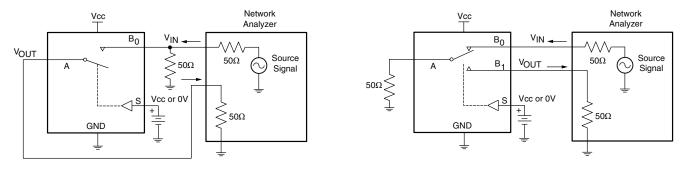
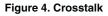
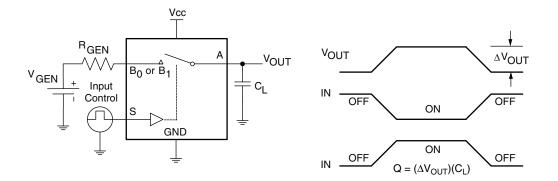


Figure 3. Off Isolation

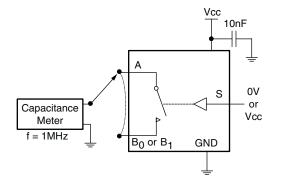




# AC Loading and Waveforms (continued)







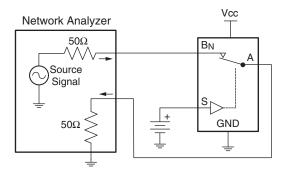


Figure 6. ON/Off Capacitance Measurement

Figure 7. Bandwidth

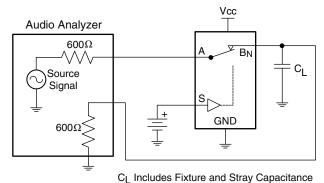
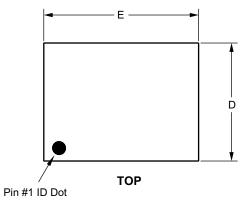
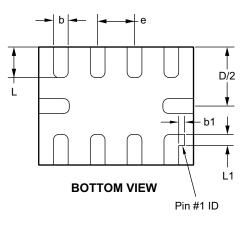
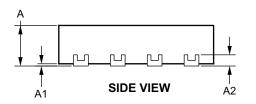


Figure 8. Harmonic Distortion

# Package Dimensions, QFN-10



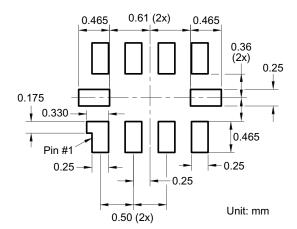




Symbols	Min.	Nom.	Max.			
А	0.50	0.55	0.60			
A1	0.00		0.05			
A2	0.152 REF.					
b	0.15	0.25				
b1	0.08 REF.					
D	1.55	1.65				
E	2.05	2.15				
е	0	).50 BSC	;			
L	0.365 0.415 0.465					
L1	0.15 REF.					

#### **Dimensions in inches**

Min.	Nom.	Max.								
0.020	0.022	0.024								
0.00	—	0.002								
0.006 REF.										
0.006	0.010									
0.003 REF.										
0.061	0.065									
0.081	0.085									
0	.020 BS	С								
0.014 0.016 0.01										
0.	.006 REI	=.								
	0.020 0.00 0.006 0.061 0.081 0.081 0.014	0.020 0.022 0.00 −− 0.006 REF 0.006 0.008 0.003 REF 0.061 0.063 0.081 0.083 0.081 0.083								

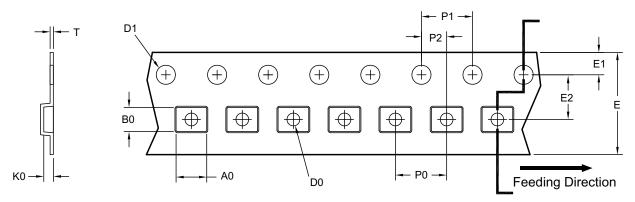


## Note:

1. Controlling dimension is millimeter. Converted inch dimensions are not necessarily exact.

## **Tape and Reel Dimensions, QFN-10**

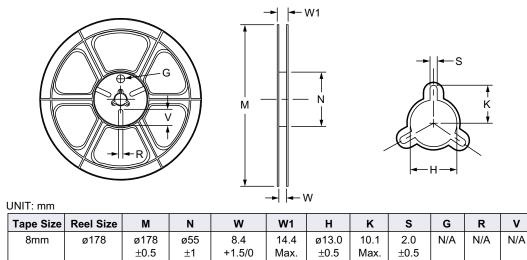
## **Carrier Tape**



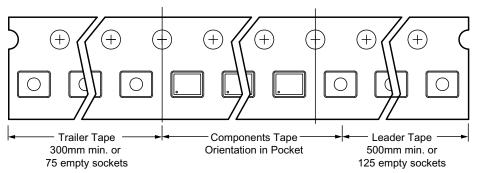
#### UNIT: mm

Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
QFN 2.1 x 1.6	0.76	1.21	0.53	0.50	1.5	8.00	1.75	3.50	4.00	4.00	2.00	0.254
(8mm)	±0.05	±0.05	±0.05	±0.05	±0.10	+0.30/-0.10	±0.10	±0.05	±0.10	±0.10	±0.05	±0.02

Reel

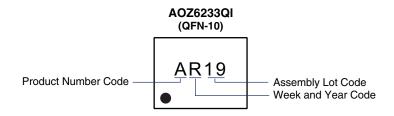


### Leader/Trailer and Orientation





## Part Marking



This datasheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

### LIFE SUPPORT POLICY

ALPHA & OMEGA SEMICONDUCTOR PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user. 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.